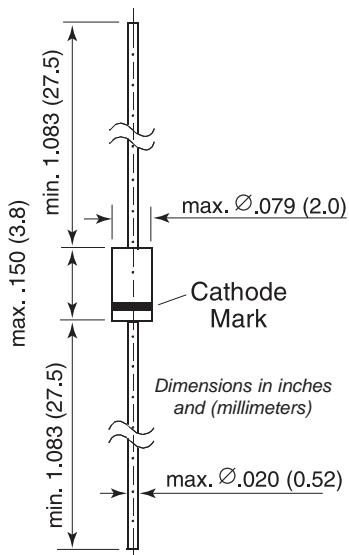



DO-204AH (DO-35 Glass)


Features

- For general purpose applications.
- This diode features low turn-on voltage. This device is protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- This diode is also available in the MiniMELF case with type designation BAS85.

Mechanical Data

Case: DO-35 Glass Case

Weight: approx. 0.13g

Packaging Codes/Options:

D7/10K per 13" reel (52mm tape), 20K/box
D8/10K per Ammo tape (52mm tape), 20K/box

Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Continuous Reverse Voltage	V _R	30	V
Forward Continuous Current at T _{amb} = 25°C	I _F	200 ⁽¹⁾	mA
Peak Forward Current at T _{amb} = 25°C	I _{FM}	300 ⁽¹⁾	mA
Surge Forward Current at t _p < 1s, T _{amb} = 25°C	I _{FSM}	600 ⁽¹⁾	mA
Power Dissipation at T _{amb} = 65°C	P _{tot}	200 ⁽¹⁾	mW
Thermal Resistance Junction to Ambient Air	R _{θJA}	430 ⁽¹⁾	°C/W
Maximum Junction Temperature	T _j	125	°C
Ambient Operating Temperature Range	T _A	-65 to +125	°C
Storage Temperature Range	T _s	-65 to +150	°C

Electrical Characteristics

(T_j = 25°C unless otherwise noted)

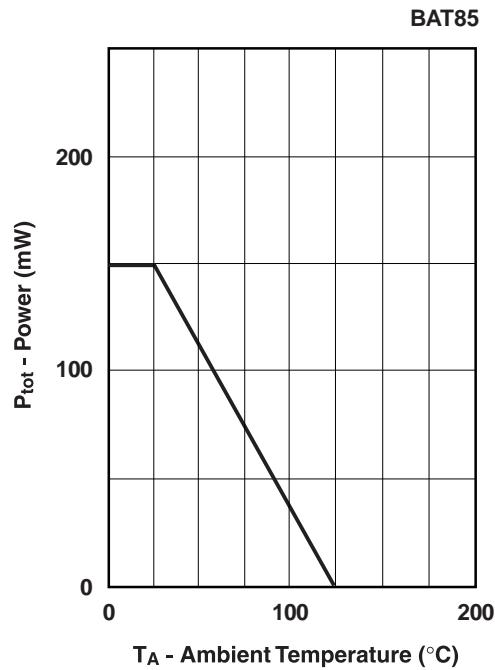
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V _{(BR)R}	I _R = 10µA (pulsed)	30	—	—	V
Leakage Current	I _R	V _R = 25V	—	—	2	µA
Forward Voltage Pulse Test t _p < 300 µs, δ < 2%	V _F	I _F = 0.1mA	—	—	0.24	V
		I _F = 1mA	—	—	0.32	
		I _F = 10mA	—	—	0.4	
		I _F = 30mA	—	0.5	—	
		I _F = 100mA	—	—	0.8	
Capacitance	C _{tot}	V _R = 1V, f = 1MHz	—	—	10	pF
Reverse Recovery Time	t _{rr}	I _F = 10mA to I _R = 10mA to I _R = 1mA	—	—	5	ns

Note: (1) Valid provided that leads at a distance of 4mm from case are kept at ambient temperature

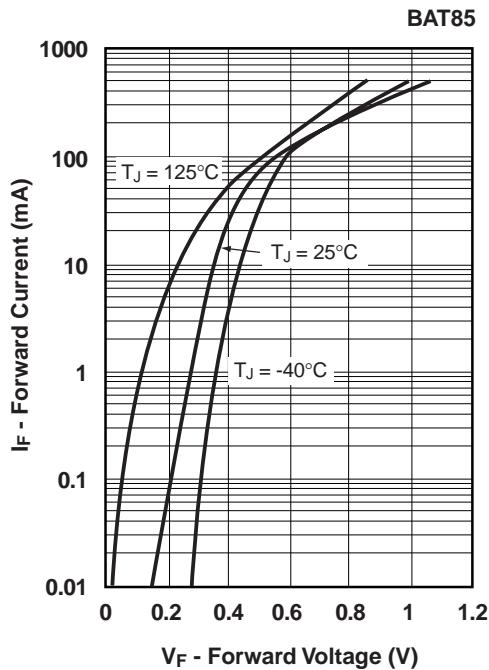
Schottky Diode

Ratings and Characteristic Curves

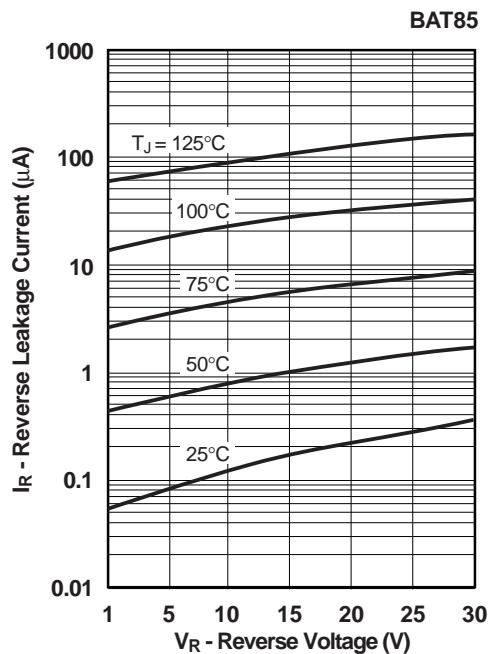
Admissible Power Dissipation vs. Ambient Temperature



Typical Instantaneous Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance

